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seminars ECUSA 2015



“GaN and Graphene: Extreme Materials for the Future of Electronics”

After dominating the electronics industry during the last forty years, Silicon is reaching its ultimate limit. New semiconductor materials like Gallium Nitride (GaN) and graphene have the potential to push electronics for another forty years. More than 20% of the world's energy consumption could be saved by using GaN in lighting and power electronics, while graphene will enable ubiquitous electronics, embedded on every object around us.

Please, **RSVP here** (free): <https://www.eventbrite.com/e/tomas-palacios-registration-19495218724>

TIME

December 10, 2015
From 6:15 to 8:30 pm

PLACE

Real Colegio Complutense
26 Trowbridge Street
Cambridge, MA 02138

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